

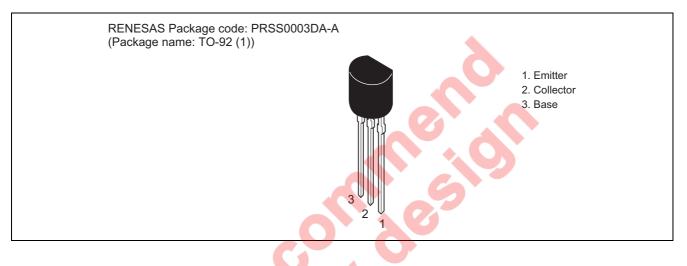
Silicon PNP Epitaxial

REJ03G0635-0300 (Previous ADE-208-1007A) Rev.3.00 Aug.10.2005

Application

Low frequency low noise amplifier

Outline



Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
ltem 🔶	Symbol	2SA1084	2SA1085	Unit
Collector to base voltage	V _{CBO}	-90	-120	V
Collector to emitter voltage	V _{CEO}	-90	-120	V
Emitter to base voltage	V _{EBO}	-5	-5	V
Collector current	Ic	-100	-100	mA
Emitter current	Ι _Ε	100	100	mA
Collector power dissipation	Pc	400	400	mW
Junction temperature	Tj	150	150	°C
Storage temperature	Tstg	-55 to +150	–55 to +150	°C



Electrical Characteristics

 $(Ta = 25^{\circ}C)$

		2SA1084		2SA1085					
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	V _{(BR)CBO}	-90	—	—	-120	_		V	$I_{\rm C} = -10 \ \mu {\rm A}, \ I_{\rm E} = 0$
Collector to emitter breakdown voltage	V _{(BR)CEO}	-90	—	—	-120	—	_	V	$I_{C} = -1 \text{ mA},$ $R_{BE} = \infty$
Emitter to base breakdown voltage	V _{(BR)EBO}	-5	—	—	-5	—	_	V	$I_E = -10 \ \mu A, \ I_C = 0$
Collector cutoff current	I _{CBO}	_		-0.1	_	_	-0.1	μA	$V_{CB} = -50 \text{ V}, I_E = 0$
Emitter cutoff current	I _{EBO}	_		-0.1	_	_	-0.1	μA	$V_{EB} = -2 V, I_C = 0$
DC current transfer ratio	h _{FE} * ¹	250	—	800	250	_	800		$V_{CE} = -12 \text{ V},$ $I_{C} = -2 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}		_	-0.2	—	_	-0.2	V	$I_{\rm C} = -10 \text{ mA},$ $I_{\rm B} = -1 \text{ mA}$
Base to emitter voltage	V _{BE}		-0.6	—	_	-0.6	P	V	$V_{CE} = -12 \text{ V},$ $I_{C} = -2 \text{ mA}$
Gain bandwidth product	f⊤		90	—	_	90		MHz	V _{CE} = -12 V, I _C = -2 mA
Collector output capacitance	Cob		3.5	—		3.5		pF	$V_{CB} = -10 \text{ V}, I_E = 0,$ f = 1 MHz
Noise voltage referred to input	en		0.5			0.5	5	nV/ √Hz	$V_{CE} = -6V,$ $I_{C} = -10 \text{ mA},$ f = 1 kHz, $R_{g} = 0, \Delta f = 1\text{ Hz}$

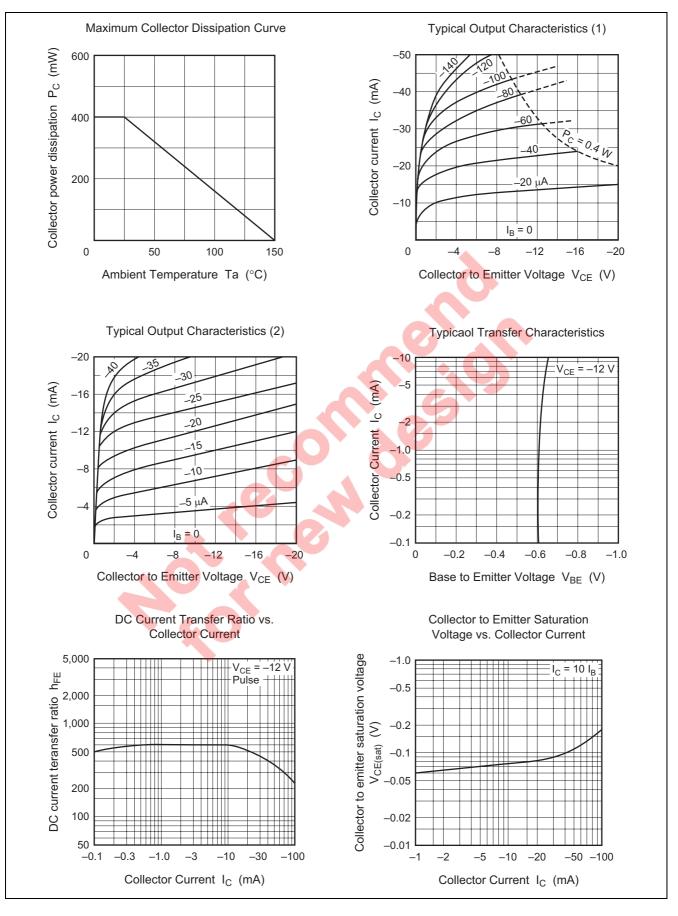
Note: 1. The 2SA1084 and 2SA1085 are grouped by hre as follows.

Ε D 250 to 500 400 to 800

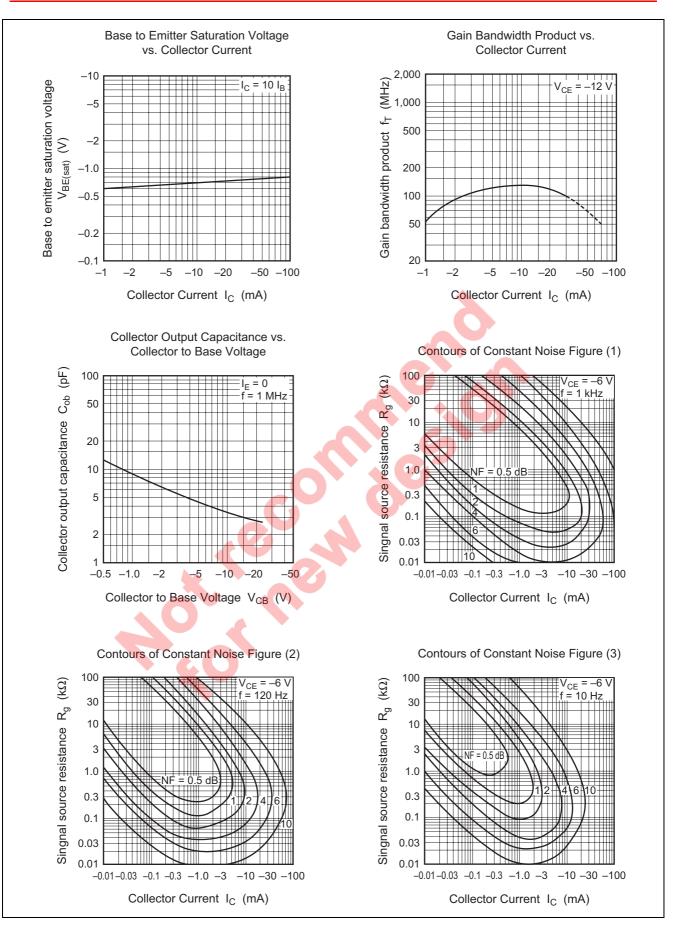
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Main Characteristics

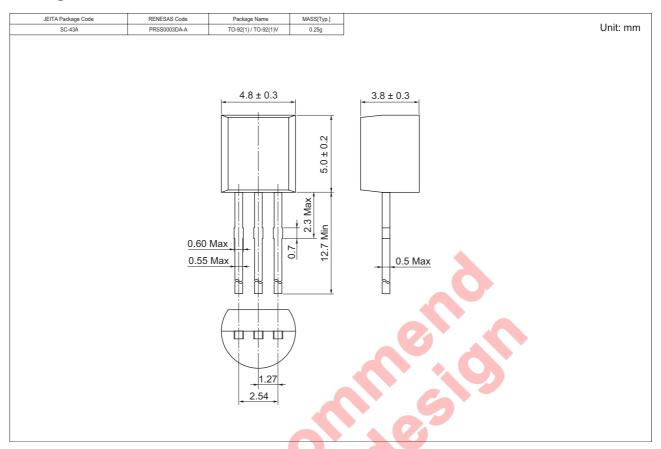








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SA1084ETZ-E	2500	Hold Box, Radial Taping
2SA1085DTZ-E		
2SA1085ETZ-E		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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